

# Monolithic Amplifier

Mini-Circuits

50Ω DC to 6 GHz

#### **THE BIG DEAL**

- Gain, 10 dB typ.
- High Pout, P1dB 19.5 dBm typ.
- High IP3, 41 dBm typ. at 1 GHz
- Ruggedized design
- Fixed 5V operation
- Unconditionally stable
- Excellent ESD Protection
- Transient protected, US patent 6,943,629
- Low additive phase noise, typically -171 dBc/Hz @10 KHz



Generic photo used for illustration purposes only

CASE STYLE: DF782

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

LTE Performance

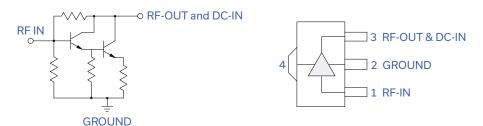
#### **APPLICATIONS**

- Base station infrastructure
- Portable Wireless
- CATV & DBS
- MMDS & Wireless LAN
- LTE
- Suitable for low phase noise applications

#### **PRODUCT OVERVIEW**

GVA-81+ (RoHS compliant) is a wideband amplifier offering high dynamic range. It has repeatable performance from lot to lot and is enclosed in a SOT-89 package. It uses patented Transient Protected Darlington configuration and is fabricated using InGaP HBT technology.

#### SIMPLIFIED SCHEMATIC AND PIN DESCRIPTION



Function	Pin Number	Description
RF IN	1	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
RF-OUT and DC-IN	3	RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit", Fig. 2
GND	2,4	Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance.

A. Suitability for model replacement within a particular system must be determined by and is solely the responsibility of the customer based on, among other things, electrical performance criteria, stimulus conditions, application, compatibility with other components and environmental conditions and stresses. B. The RFMD SBB4089Z part number is used for identification and comparison purposes only.

> REV. C ECO-010563 GVA-81+ 211108

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#### ELECTRICAL SPECIFICATIONS<sup>(1)</sup> AT 25°C AND 5V, UNLESS NOTED

Parameter	Condition (GHz)	Min.	Тур.	Max.	Units
Frequency Range <sup>2</sup>		DC		6	GHz
	0.1	9.5	10.5	11.5	dB
	1.0	_	10.5	_	
Gain	2.0	9.0	10.0	11.0	
	3.0	_	9.3	_	
	4.0	8.0	8.7	10.0	
	6.0	_	8.1	_	
	0.1	_	0.0005	_	dB/°C
	1.0	_	0.0010	_	
npMagnitude of Gain Variation versus Temperature <sup>(3)</sup>	2.0	_	0.0016	0.005	
values are negative)	3.0	_	0.0020	_	
	4.0	_	0.0025	_	
	6.0	_	0.0036	_	
	0.1	_	38.0	_	dB
	1.0	_	27.0	_	
	2.0	17	20.1	_	
nput Return Loss	3.0	_	17.4	_	
	4.0	_	16.9	_	
	6.0	_	18.5	_	
Reverse Isolation	2.0		20.8		dB
	0.1	18.0	19.1	_	dBm
	1.0	18.0	19.1	_	
	2.0	18.0	19.7	_	
Output Power at 1dB Compression	3.0	_	20.0	_	
	4.0	_	19.4	_	
	6.0	_	17.7	_	
	0.1	_	42.0	_	dBm
	1.0	_	41.3	_	
	2.0	34	36.6	_	
Dutput IP3	3.0	_	35.0	_	
	4.0	_	33.2	_	
	6.0	_	31.1	_	
	0.1	_	7.3	7.9	
	1.0	_	7.3	_	dB
	2.0	_	7.4	7.9	
Noise Figure	3.0	_	7.6	_	
	4.0	_	7.7	8.2	
	6.0	_	8.3	_	
Additive Phase Noise 2 GHz, 10 KHz offset	5.0		-171		dBc/Hz
Group Delay		4.8	98		psec
Device Operating Voltage		94	5.0	5.2	V
Device Operating Current		5.	103	112	mA
Device Current Variation vs. Temperature			62		µA/°C
Device Current Variation vs. Temperature			0.036		mA/mV
			0.050		111/5/1111

Measured on Mini-Circuits test board TB-313. See Characterization Test Circuit (Fig. 1)
Guaranteed specification DC\*-7 GHz. \*Low frequency cut off determined by external coupling capacitors and RF Choke (RFC).
(Gain at 85°C, Gain at -45°C)/130



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#### **MAXIMUM RATINGS**

Parameter	Ratings	
Operating Temperature (ground lead)	-40°C to 85°C	
Storage Temperature	-65°C to 150°C	
Operating Current at 5V	160mA	
Power Dissipation	0.855W	
Input Power	13dBm	
DC Voltage on Pin 3	5.9V	

Permanent damage may occur if any of these limits are exceeded.

Electrical maximum ratings are not intended for continuous normal operation.

#### **CHARACTERIZATION TEST CIRCUIT**

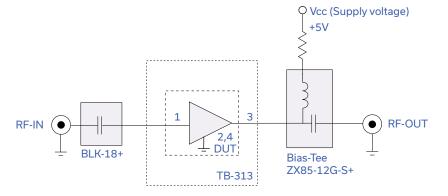


Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Test Board TB-313) Gain, Output power at 1dB compression (P1 dB) and output IP3 (OIP3) are measured using R&S Network Analyzer ZVA-24. Noise Figure measured using Agilent's N5242A PNA-X microwave network analyzer.

#### Conditions:

1. Gain and Return loss: Pin= -25dBm 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/ tone at output.

#### **RECOMMENDED APPLICATION CIRCUIT**

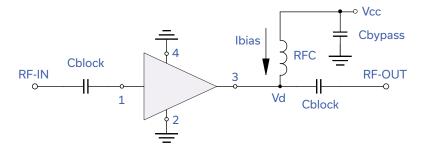


Fig 2. Test Board includes case, connectors, and components soldered to  $\mathsf{PCB}$ 

#### **PRODUCT MARKING**



Marking may contain other features or characters for internal lot control

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### ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASH BOARD. TO ACCESS CLICK HERE

	Data Table	
Performance Data	Swept Graphs	
	S-Parameter (S2P Files) Data Set (.zip file)	
Case Style	DF782 (SOT 89) Plastic package, exposed paddle lead finish: Matte-tin	
Tape & Reel Standard quantities available on reel	F55 7″ reels with 20, 50, 100, 200, 500 or 1K devices	
Suggested Layout for PCB Design	PL-255	
Evaluation Board	TB-410-81+	
Environmental Ratings	ENV08T1	

#### **ESD RATING**

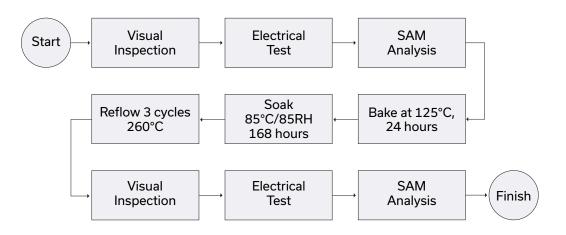
Human Body Model (HBM): Class 1C (1000v to < 2000v) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M2 (100V to < 200V) in accordance with ANSI/ESD STM 5.2 - 1999

#### **MSL RATING**

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020D

#### **MSL TEST FLOW CHART**



#### NOTES

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard. Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp

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